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# **BLF6G20-180RN**; Power LDMOS transistor Rev. 2 — 1 September 2015

**AMPLEON** 

Product data sheet

# **Product profile**

### **General description**

180 W LDMOS power transistor for base station applications at frequencies from 1800 MHz to 2000 MHz.

Table 1. Typical performance

Typical RF performance at  $T_{case} = 25$  °C in a class-AB production test circuit.

Mode of operation	f	V <sub>DS</sub>	P <sub>L(AV)</sub>	Gp	η <sub>D</sub>	IMD3	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
2-carrier WCDMA	1930 to 1990	30	40	17.2	27	-38 <u>[1]</u>	-41 <sup>[1]</sup>

<sup>[1]</sup> Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7 dB at 0.01 % probability on CCDF per carrier; carrier spacing 10 MHz.

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

### 1.2 Features

- Typical 2-carrier WCDMA performance at frequencies of 1930 MHz and 1990 MHz, a supply voltage of 30 V and an  $I_{Dq}$  of 1400 mA:
  - Average output power = 40 W
  - ◆ Power gain = 17.2 dB
  - ◆ Efficiency = 27 %
  - ◆ IMD3 = -41 dBc
  - ◆ ACPR = -38 dBc
- Easy power control
- Integrated ESD protection
- Enhanced ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1800 MHz to 2000 MHz)
- Internally matched for ease of use

 Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

 RF power amplifiers for GSM, GSM EDGE, W-CDMA and CDMA base stations and multi carrier applications in the 1800 MHz to 2000 MHz frequency range

# 2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF6G20-1	180RN (SOT502A)			
1	drain			_
2	gate		5 3	, <b>L</b> ]
3	source	[1]		2 —
				3 sym112
BLF6G20L	S-180RN (SOT502B)			<b>5</b>
1	drain			
2	gate		1 3	1 ,
3	source	<u>[1]</u>	2   3	2
				3
				sym112

<sup>[1]</sup> Connected to flange.

# 3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLF6G20-180RN	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A			
BLF6G20LS-180RN	-	earless flanged LDMOST ceramic package; 2 leads	SOT502B			

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
I <sub>D</sub>	drain current		-	49	Α
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	225	°C

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### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Туре	Тур	Unit
$R_{\text{th(j-case)}}$	thermal resistance from	$T_{case}$ = 80 °C;	BLF6G20-180RN	0.50	K/W
	junction to case	$P_L = 40 W$	BLF6G20LS-180RN	0.37	K/W

### 6. Characteristics

Table 6. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.9 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 270 mA	1.4	2.0	2.4	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS}$ = 28 V; $I_{D}$ = 1.62 A	1.5	2.0	2.5	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	5	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	40	45	-	Α
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 13 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	450	nA
9fs	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 13.5 A	-	19.5	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 9.45 \text{ A}$	-	0.06	-	Ω
C <sub>rs</sub>	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 30 \text{ V};$ f = 1 MHz	-	3.3	-	pF

# 7. Application information

Table 7. Application information

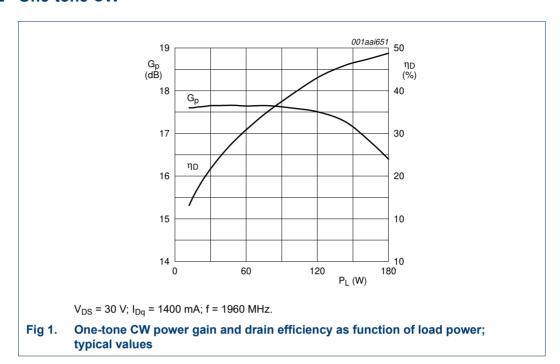
Mode of operation: 2-carrier WCDMA; PAR = 7 dB at 0.01 % probability on the CCDF;  $f_1$  = 1932.5 MHz;  $f_2$  = 1942.5 MHz;  $f_3$  = 1977.5 MHz;  $f_4$  = 1987.5 MHz; RF performance at  $V_{DS}$  = 30 V;  $I_{Dq}$  = 1400 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	40	-	W
Gp	power gain	$P_{L(AV)} = 40 \text{ W}$	16.3	17.2	-	dB
$RL_{in}$	input return loss	$P_{L(AV)} = 40 \text{ W}$	-	-15	-10	dB
$\eta_{D}$	drain efficiency	$P_{L(AV)} = 40 \text{ W}$	24	27	-	%
IMD3	third order intermodulation distortion	$P_{L(AV)} = 40 \text{ W}$	-	-38	-35	dBc
ACPR	adjacent channel power ratio	$P_{L(AV)} = 40 \text{ W}$	-	-41	-39	dBc

### 7.1 Ruggedness in class-AB operation

The BLF6G20-180RN and BLF6G20LS-180RN are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 30 V;  $I_{Dq}$  = 1400 mA;  $P_{L}$  = 180 W (CW); f = 1990 MHz.

### 7.2 One-tone CW



### 7.3 Two-tone CW

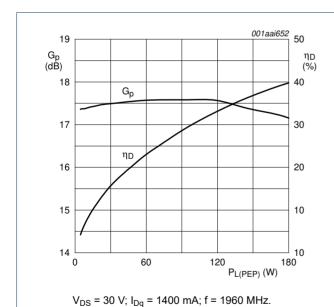
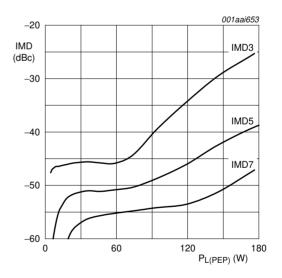


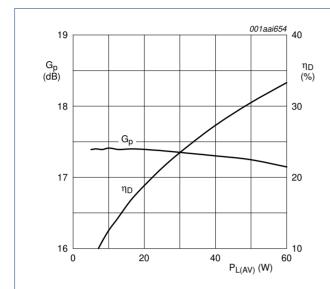
Fig 2. Two-tone CW power gain and drain efficiency as function of peak envelope load power; typical values



 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1400 mA; f = 1960 MHz.

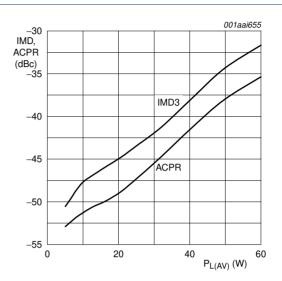
Fig 3. Two-tone CW intermodulation distortion as a function of peak envelope load power; typical values

### 7.4 2-carrier W-CDMA



 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1400 mA; f = 1960 MHz (±5 MHz); carrier spacing 10 MHz.

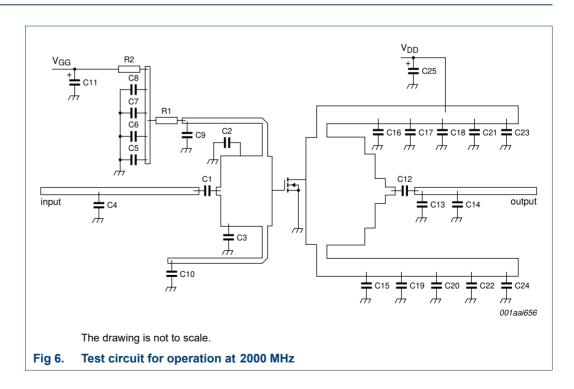
Fig 4. 2-carrier W-CDMA power gain and drain efficiency as function of average load power; typical values



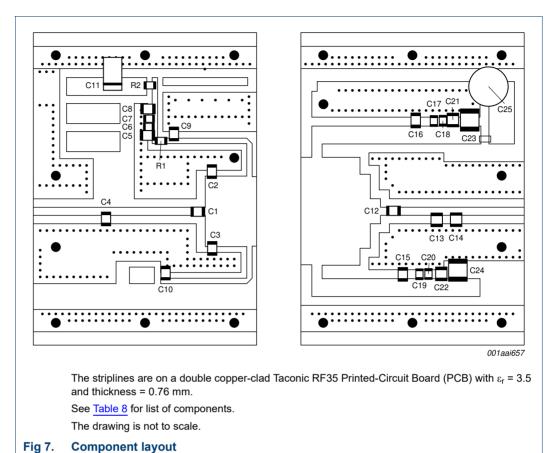
 $V_{DS}$  = 30 V;  $I_{Dq}$  = 1400 mA; f = 1960 MHz (±5 MHz); carrier spacing 10 MHz.

Fig 5. 2-carrier W-CDMA adjacent channel power ratio and third order intermodulation distortion as function of average load power; typical values

# 8. Test information



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rig 7. Component layout

**Table 8.** List of components (see Figure 6 and Figure 7)
The Printed-Circuit Board (PCB) used is a double copper-clad Taconic RF35 with  $\varepsilon_r = 3.5$  and thickness = 0.76 mm.

Component	Description	Value		Remarks
C1	multilayer ceramic chip capacitor	1.9 pF	[1]	ATC 100B or capacitor of same quality
C2	multilayer ceramic chip capacitor	2.0 pF	[1]	ATC 100B or capacitor of same quality
C3	multilayer ceramic chip capacitor	0.6 pF	[1]	ATC 100B or capacitor of same quality
C4	multilayer ceramic chip capacitor	1.8 pF	[1]	ATC 100B or capacitor of same quality
C5, C12, C15, C16	multilayer ceramic chip capacitor	11 pF	[1]	ATC 100B or capacitor of same quality
C6, C7, C17, C18, C19, C20	multilayer ceramic chip capacitor	220 nF		Vishay or capacitor of same quality
C8	multilayer ceramic chip capacitor	100 nF		Vishay or capacitor of same quality
C9, C10	multilayer ceramic chip capacitor	12 pF	[1]	ATC 100B or capacitor of same quality
C11	multilayer ceramic chip capacitor	10 μF		
C13	multilayer ceramic chip capacitor	1.0 pF	[1]	ATC 100B or capacitor of same quality
C14	multilayer ceramic chip capacitor	0.3 pF	[1]	ATC 100B or capacitor of same quality
C21, C22	multilayer ceramic chip capacitor	1.5 μF		
C23, C24	multilayer ceramic chip capacitor	10 μF; 50 V		TDK or capacitor of same quality
C25	electrolytic capacitor	220 μF; 63 V		

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**Power LDMOS transistor** 

Table 8. List of components (see Figure 6 and Figure 7) ...continued

The Printed-Circuit Board (PCB) used is a double copper-clad Taconic RF35 with  $\varepsilon_r = 3.5$  and thickness = 0.76 mm.

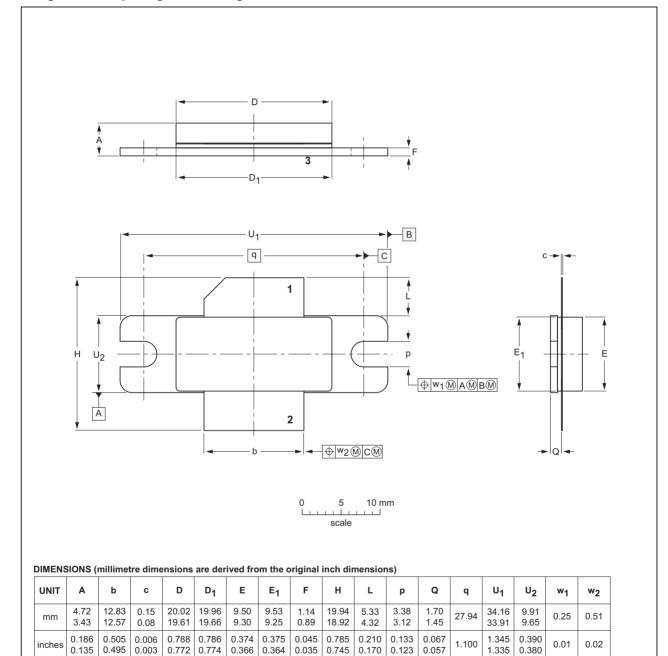
Component	Description	Value	Remarks
L1	ferrite SMD bead	-	Ferroxcube BDS 3/3/4.6-4S2 or equivalent
R1	SMD resistor	2.7 Ω	
R2	SMD resistor	6.8 Ω	

<sup>[1]</sup> Solder vertically.

# 9. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

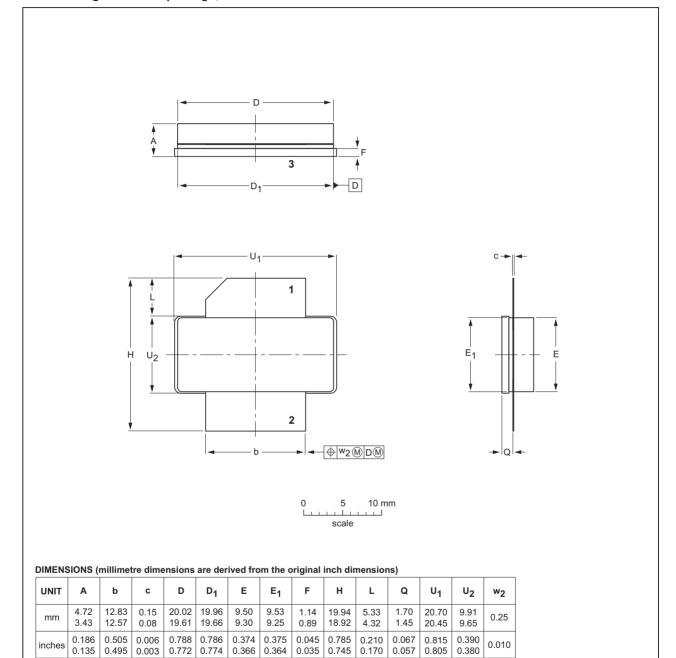


OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT502A						<del>-03-01-10</del> 12-05-02	

Fig 8. Package outline SOT502A

### Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE	OUTLINE REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT502B						<del>07-05-09</del> 12-05-02

Fig 9. Package outline SOT502B

# 10. Abbreviations

Table 9. Abbreviations

14510 01	7.155.107.14.107.15
Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CDMA	Code Division Multiple Access
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
EDGE	Enhanced Data rates for GSM Evolution
GSM	Global System for Mobile communications
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

# 11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF6G20-180RN_20LS-180RN#2	20150901	Product data sheet	-	BLF6G20-180RN_20LS-180RN _1
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> </ul>			
	Legal texts have been adapted to the new company name where appropriate.			
BLF6G20-180RN_20LS-180RN_1	20081117	Product data sheet	-	-

# 12. Legal information

### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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# **AMPLEON**

# **BLF6G20(LS)-180RN**

**Power LDMOS transistor** 

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